

Features

- $BV_{CEO} > 40V$
- $I_C = 200mA$ High Collector Current
- Pair of NPN Transistors that are Intrinsically Matched (Note 1)
- 2% Matching on Current Gain (h_{FE})
- 2mV Matching on Base-Emitter Voltage (V_{BE})
- Fully Internally Isolated in a Small Surface Mount Package
- **Totally Lead-Free & Fully RoHS Compliant (Notes 2 & 3)**
- **Halogen and Antimony Free. "Green" Device (Note 4)**
- The DMMT3904WQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

<https://www.diodes.com/quality/product-definitions/>

Mechanical Data

- Case: SOT363
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish — Matte Tin Finish. Solderable per MIL-STD-202, Method 208 Ⓔ
- Weight: 0.006 grams (Approximate)

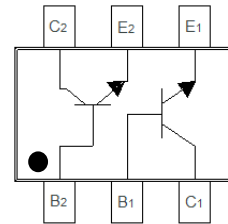
Applications

- Current Mirrors
- Differential and Instrumentation Amplifiers
- Comparators

SOT363



Top View



Device Schematic and Pin-Out
Top View

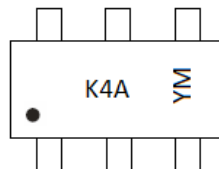
Ordering Information (Note 5)

Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
DMMT3904WQ-7-F	Automotive	K4A	7	8	3,000

- Notes:
1. Intrinsically matched pair as this is built with adjacent die from the same wafer.
 2. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
 3. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 4. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 5. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

Marking Information

SOT363



K4A = Product Type Marking Code
YM = Date Code Marking
Y = Year (ex: H = 2020)
M = Month (ex: 2 = February)

Date Code Key

Year	2014	...	2020	2021	2022	2023	2024	2025	2026	2027	2028	2029
Code	B	...	H	I	J	K	L	M	N	O	P	R
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CB0}	60	V
Collector-Emitter Voltage	V _{CEO}	40	V
Emitter-Base Voltage	V _{EB0}	6.0	V
Collector Current	I _C	200	mA

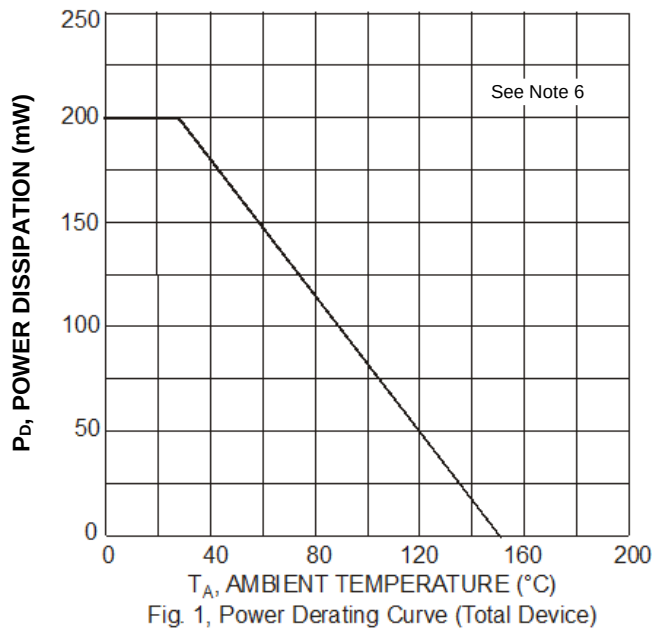
Thermal Characteristics – Total Device (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 6) Total Device	P _D	200	mW
Thermal Resistance, Junction to Ambient (Note 6)	R _{θJA}	625	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-65 to +150	°C

ESD Ratings (Note 7)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	C

Notes: 6. For a device mounted on minimum recommended pad layout with 1oz copper that is on a single-sided 1.6mm FR-4 PCB; the device is measured under still air conditions whilst operating in a steady-state.
 7. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

Thermal Characteristics – Total Device


Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS						
Collector-Base Breakdown Voltage	BV _{CBO}	60	—	—	V	I _C = 100μA, I _E = 0
Collector-Emitter Breakdown Voltage (Note 8)	BV _{CEO}	40	—	—	V	I _C = 1.0mA, I _B = 0
Emitter-Base Breakdown Voltage	BV _{EBO}	6.0	—	—	V	I _E = 100μA, I _C = 0
Collector Cutoff Current	I _{CEX}	—	—	50	nA	V _{CE} = 30V, V _{EB(off)} = 3.0V
Base Cutoff Current	I _{BL}	—	—	50	nA	V _{CE} = 30V, V _{EB(off)} = 3.0V
ON CHARACTERISTICS (Note 8)						
DC Current Gain	h _{FE}	40 70 100 60 30	—	— — 300 — —	—	I _C = 100μA, V _{CE} = 1.0V I _C = 1.0mA, V _{CE} = 1.0V I _C = 10mA, V _{CE} = 1.0V I _C = 50mA, V _{CE} = 1.0V I _C = 100mA, V _{CE} = 1.0V
Collector-Emitter Saturation Voltage	V _{CE(sat)}	—	—	200 300	mV	I _C = 10mA, I _B = 1.0mA I _C = 50mA, I _B = 5.0mA
Base-Emitter Saturation Voltage	V _{BE(sat)}	650 —	—	850 950	mV	I _C = 10mA, I _B = 1.0mA I _C = 50mA, I _B = 5.0mA
MATCHING CHARACTERISTICS						
DC Current Gain Matching (Note 9)	h _{FE1} / h _{FE2}	—	1	2	%	I _C = 2mA, V _{CE} = 5V
Base-Emitter Voltage Matching (Note 10)	V _{BE1} - V _{BE2}	—	1	2	mV	I _C = 2mA, V _{CE} = 5V
Collector-Emitter Saturation Voltage (Note 9)	V _{CE(sat)1} / V _{CE(sat)2}	—	1	2	%	I _C = 10mA, I _B = 1.0mA
Base-Emitter Saturation Voltage (Note 9)	V _{BE(sat)1} / V _{BE(sat)2}	—	1	2	%	I _C = 10mA, I _B = 1.0mA
SMALL SIGNAL CHARACTERISTICS						
Output Capacitance	C _{OBO}	—	—	4.0	pF	V _{CB} = 5.0V, f = 1.0MHz, I _E = 0
Input Capacitance	C _{IBO}	—	—	8.0	pF	V _{EB} = 0.5V, f = 1.0MHz, I _C = 0
Input Impedance	h _{IE}	1.0	—	10	kΩ	V _{CE} = 10V, I _C = 1.0mA, f = 1.0kHz
Voltage Feedback Ratio	h _{RE}	0.5	—	8	x 10 ⁻⁴	
Small Signal Current Gain	h _{FE}	100	—	400	—	
Output Admittance	h _{OE}	1.0	—	40	μS	
Current Gain-Bandwidth Product	f _T	300	—	—	MHz	V _{CE} = 20V, I _C = 10mA, f = 100MHz
Noise Figure	NF	—	—	5.0	dB	V _{CE} = 5.0V, I _C = 100μA, R _S = 1.0kΩ, f = 1.0kHz
SWITCHING CHARACTERISTICS						
Delay Time	t _D	—	—	35	ns	V _{CC} = 3.0V, I _C = 10mA, V _{BE(off)} = -0.5V, I _{B1} = 1.0mA
Rise Time	t _R	—	—	35	ns	
Storage Time	t _S	—	—	200	ns	
Fall Time	t _F	—	—	50	ns	

Notes: 8. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%.
9. Is the ratio of one transistor compared to the other transistor.
10. V_{BE1} - V_{BE2} is the absolute difference of one transistor compared to the other transistor.

Typical Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

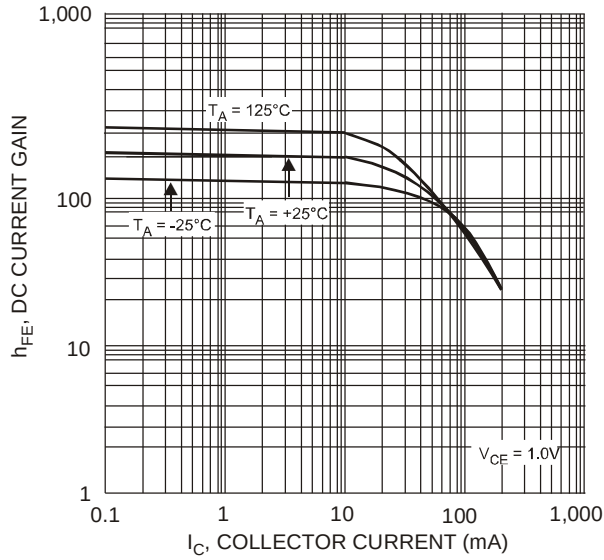


Fig. 2, Typical DC Current Gain vs. Collector Current

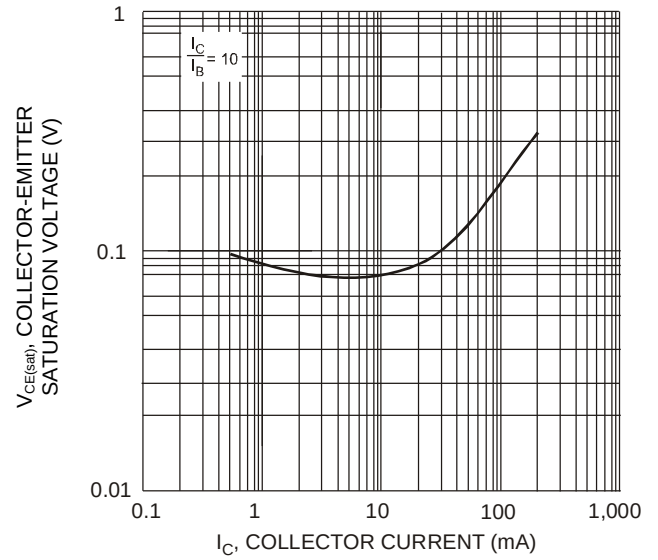


Fig. 3, Typical Collector-Emitter Saturation Voltage vs. Collector Current

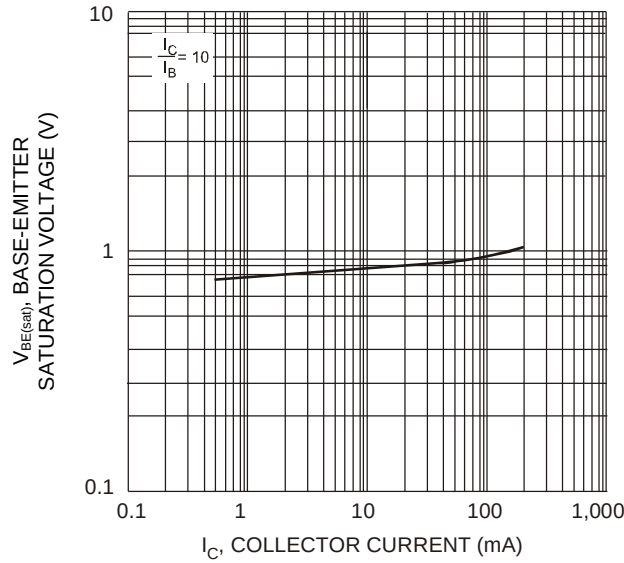


Fig. 4, Typical Base-Emitter Saturation Voltage vs. Collector Current

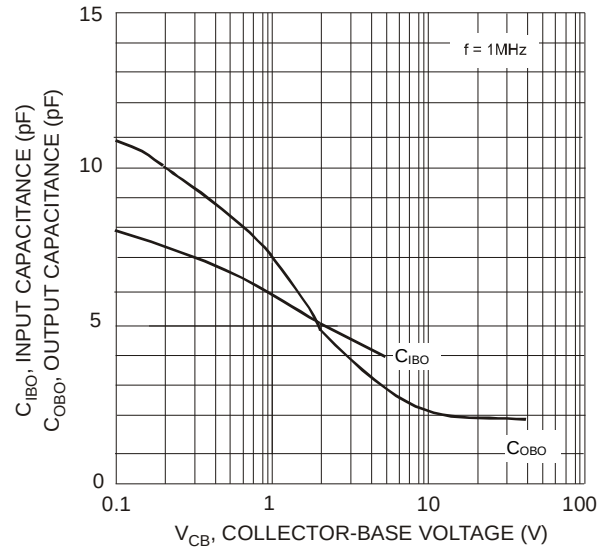
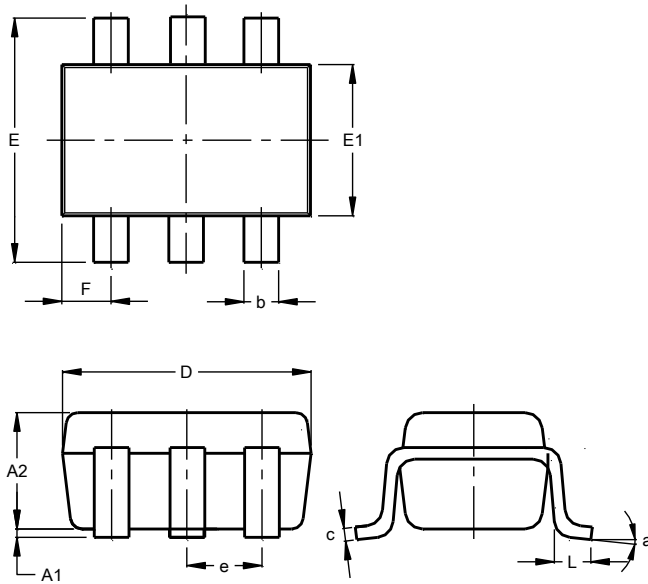


Fig. 5, Input and Output Capacitance vs. Collector-Base Voltage

Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

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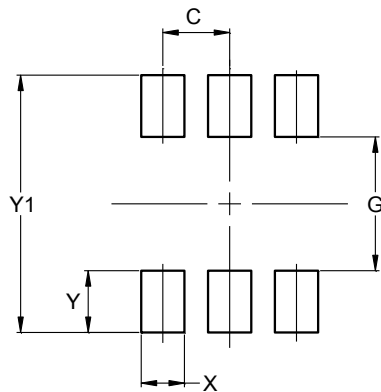


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Dim	Min	Max	Typ
A1	0.00	0.10	0.05
A2	0.90	1.00	0.95
b	0.10	0.30	0.25
c	0.10	0.22	0.11
D	1.80	2.20	2.15
E	2.00	2.20	2.10
E1	1.15	1.35	1.30
e	0.650 BSC		
F	0.40	0.45	0.425
L	0.25	0.40	0.30
a	0°	8°	--
All Dimensions in mm			

Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

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Dimensions	Value (in mm)
C	0.650
G	1.300
X	0.420
Y	0.600
Y1	2.500

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